NSN 5961-01-329-9537



Diode Semiconductor Device - Page 1 of 1

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| Inclosure Material: |
| Glass |
| Overall Length: |
| Between 0.195 inches and 0.300 inches |
| Terminal Length: |
| Between 1.000 inches and 1.500 inches |
| Overall Diameter: |
| Between 0.078 inches and 0.107 inches |
| Function For Which Designed: |
| Voltage variable capacitor |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation: |
| Do-7 |
| Mounting Method: |
| Terminal |
| Features Provided: |
| Hermetically sealed case and quality assurance level tx |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 30.0 working peak reverse voltage, peak total value and 30.0 breakdown voltage, dc |
| Current Rating Per Characteristic: |
| 10.00 microamperes forward current, average peak |
| Power Rating Per Characteristic: |
| 400.0 milliwatts small-signal input power, common-collector preset |
| Capacitance Rating In Picofarads: |
| 27.54 |
| Maximum Operating Tempurature Per Measurement Point: |
| 175.0 degrees celsius ambient air |
| Test Data Document: |
| 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification |
| format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain |
| environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Specification Data: |
| 81349-mil-s-19500/436 government specification |
| Shelf Life: |
| N/a |
| Unit Of Measure: |

Demilitarization:

No

Fiig:

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